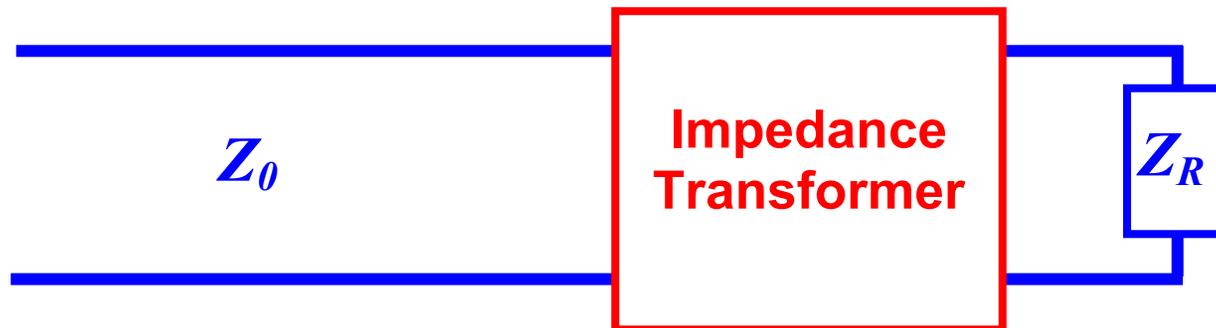


## Impedance Matching

A number of techniques can be used to eliminate reflections when the **characteristic impedance** of the line and the **load impedance** are mismatched.

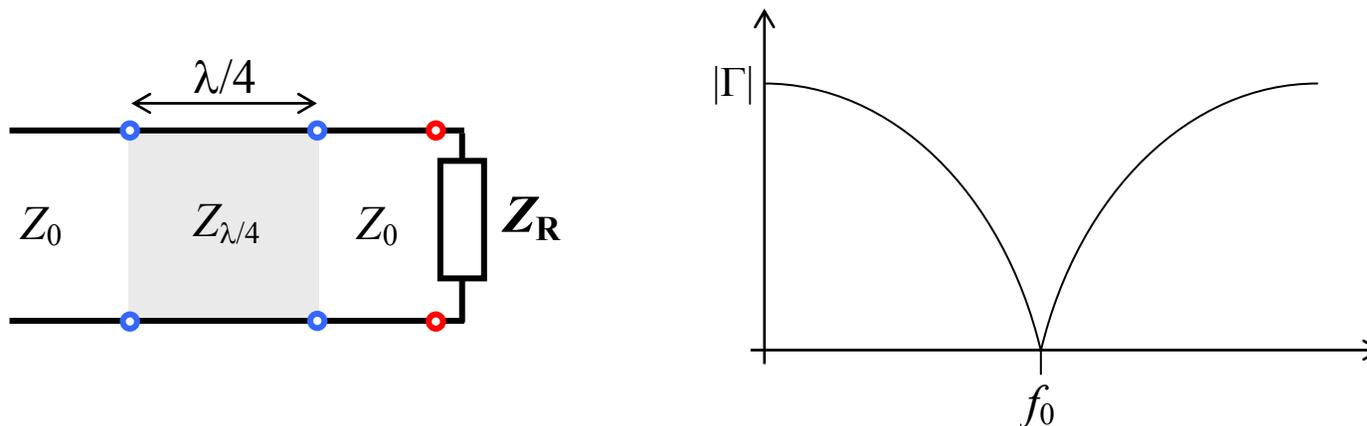
Impedance matching techniques can be designed to be effective for a **specific frequency** of operation (**narrow band techniques**) or for a given **frequency spectrum** (**broadband techniques**).

A common method of impedance matching involves the insertion of an **impedance transformer** between line and load



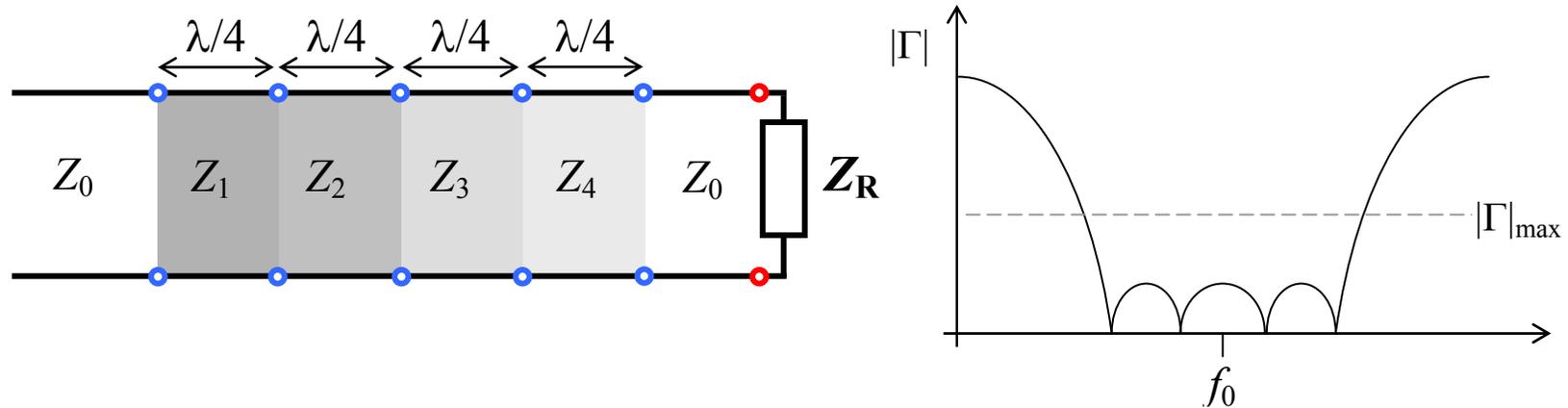
An **impedance transformer** may be realized by inserting a section of a different transmission line with appropriate characteristic impedance. A widely used approach realizes the transformer with a line of length  $\lambda/4$ .

The **quarter-wavelength** transformer provides **narrow-band** impedance matching. The design goal is to obtain zero reflection coefficient exactly at the frequency of operation.



The length of the transformer is fixed at  $\lambda/4$  for design convenience, but is also possible to realize generalized transformer lines for which the length of the transformer is a design outcome.

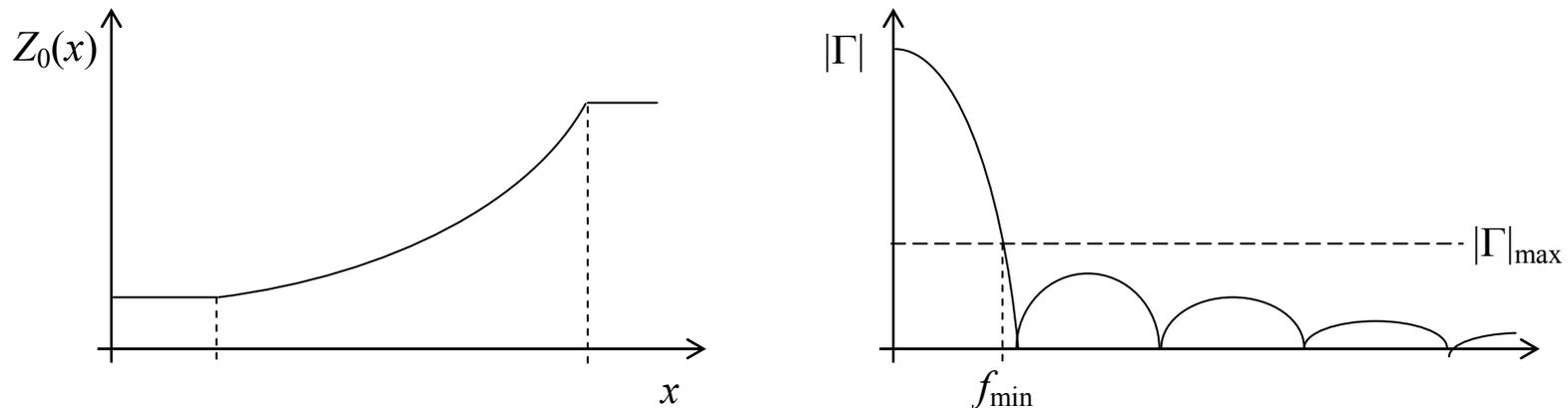
A **broadband design** may be obtained by a **cascade** of  $\lambda/4$  line sections of **gradually varying** characteristic impedance.



It is not possible to obtain exactly zero reflection coefficient for all frequencies in the desired band.

Therefore, available design approaches specify a **maximum reflection coefficient** (or maximum VSWR) which can be tolerated in the **frequency band** of operation.

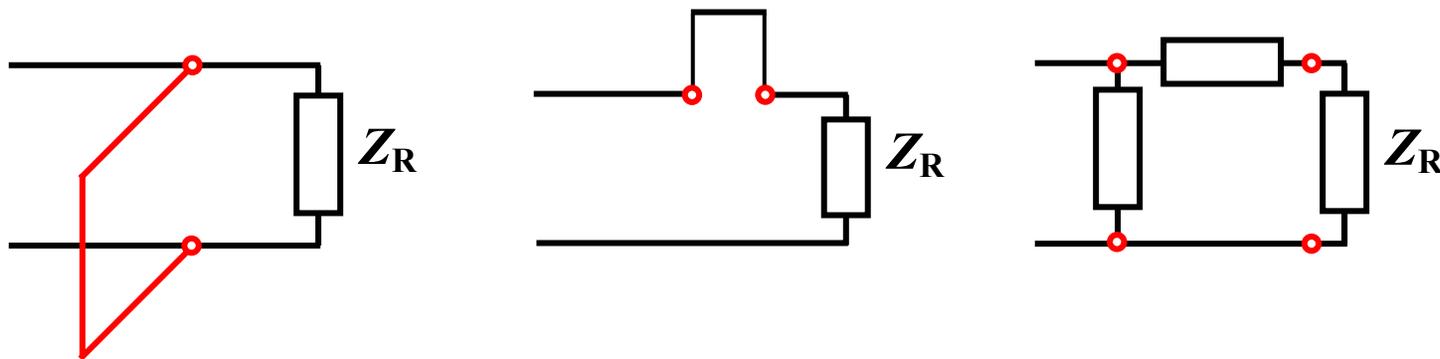
Another **broadband matching** approach may use a **tapered** line transformer with **continuously varying** characteristic impedance along its length. In this case, the design obtains **reflection coefficients lower** than a specified tolerance at **frequencies exceeding** a minimum value.



Various taper designs are available, including linear, exponential, and raised-cosine impedance profiles. An optimal design (due to Klopfenstein) involves discontinuity of the impedance at the transformer ends.

Another narrow-band approach involves the insertion of a shunt imaginary admittance on the line. Often, the admittance is realized with a section (or stub) of transmission line and the technique is commonly known as **stub matching**. The end of the stub line is short-circuited or open-circuited, in order to realize an imaginary admittance. Designs are also available for two or three shunt admittances placed at specified locations on the line.

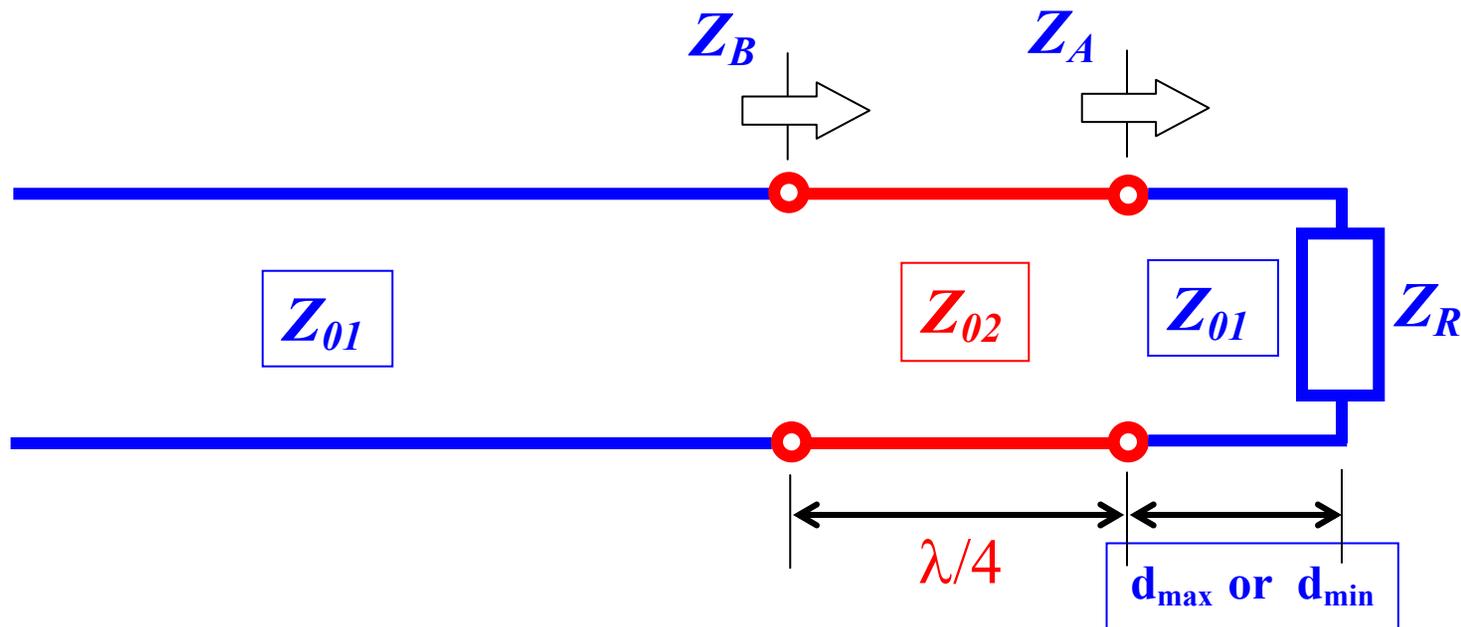
Other narrow-band examples involve the insertion of a series impedance (stub) along the line, and the insertion of a series and a shunt element in L-configuration.



The theory for several basic narrow-band matching techniques is detailed in the following. Note that the effect of **loss** in the transmission lines is always **neglected**.

## Matching I: Impedance Transformers

- **Quarter Wavelength Transformer** – A simple narrow band **impedance transformer** consists of a transmission line section of length  $\lambda/4$



The **impedance transformer** is positioned so that it is connected to a **real** impedance  $Z_A$ . This is always possible if a location of **maximum** or **minimum** voltage standing wave pattern is selected.

Consider a general load impedance with its corresponding load reflection coefficient

$$Z_R = R_R + jX_R \quad ; \quad \Gamma_R = \frac{Z_R - Z_{01}}{Z_R + Z_{01}} = |\Gamma_R| \exp(j\phi)$$

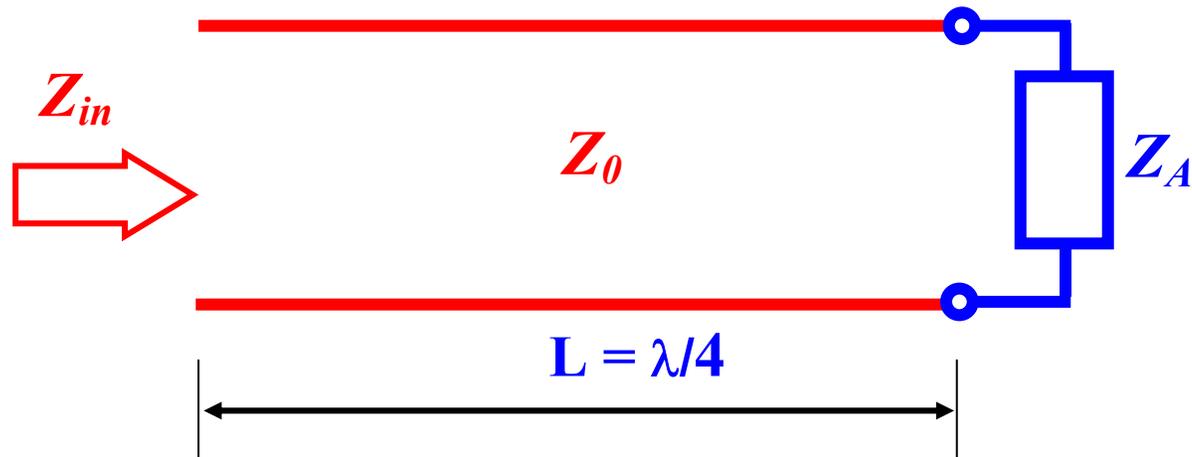
If the transformer is inserted at a location of **voltage maximum**  $d_{\max}$

$$Z_A = Z_{01} \frac{1 + \Gamma(d)}{1 - \Gamma(d)} = Z_{01} \frac{1 + |\Gamma_R|}{1 - |\Gamma_R|}$$

If it is inserted instead at a location of **voltage minimum**  $d_{\min}$

$$Z_A = Z_{01} \frac{1 + \Gamma(d)}{1 - \Gamma(d)} = Z_{01} \frac{1 - |\Gamma_R|}{1 + |\Gamma_R|}$$

Consider now the input impedance of a line of length  $\lambda/4$



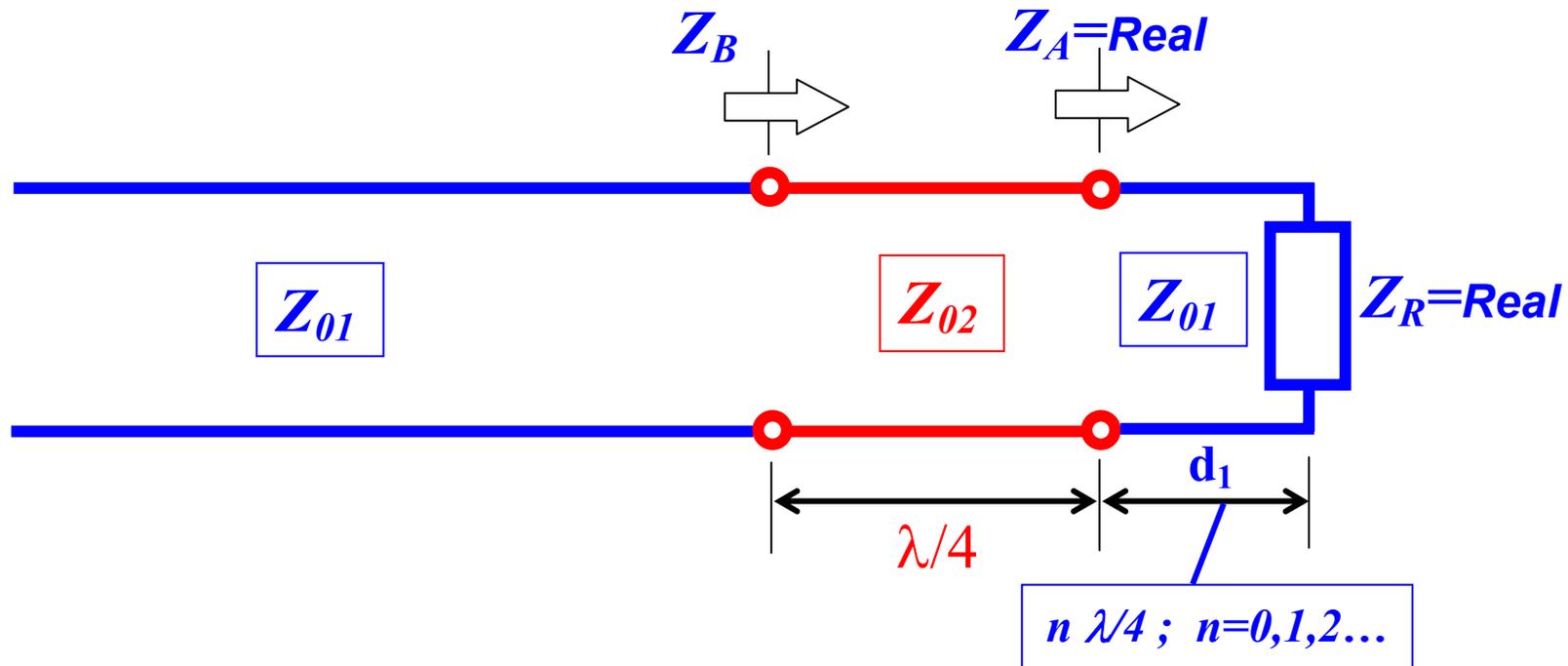
Since:

$$Z_A = Z_0 \frac{1 + \Gamma(d)}{1 - \Gamma(d)} = Z_0 \frac{1 - |\Gamma_R|}{1 + |\Gamma_R|}$$

we have

$$Z_{in} = \lim_{\tan(\beta L) \rightarrow \infty} Z_0 \frac{Z_A + jZ_0 \tan(\beta L)}{jZ_A \tan(\beta L) + Z_0} \rightarrow \frac{Z_0^2}{Z_A}$$

Note that if the **load** is **real**, the voltage standing wave pattern at the load is **maximum** when  $Z_R > Z_{01}$  or **minimum** when  $Z_R < Z_{01}$ . The transformer can be connected directly at the **load** location or at a distance from the load corresponding to a multiple of  $\lambda/4$ .



If the **load impedance** is **real** and the transformer is inserted at a distance from the load equal to an **even** multiple of  $\lambda/4$ , then

$$Z_A = Z_R \quad ; \quad d_1 = 2n \frac{\lambda}{4} = n \frac{\lambda}{2}$$

but if the distance from the load is an **odd** multiple of  $\lambda/4$

$$Z_A = \frac{Z_{01}^2}{Z_R} \quad ; \quad d_1 = (2n+1) \frac{\lambda}{4} = n \frac{\lambda}{2} + \frac{\lambda}{4}$$

The **input impedance** of the impedance transformer **after inclusion in the circuit** is given by

$$Z_B = \frac{Z_{02}^2}{Z_A}$$

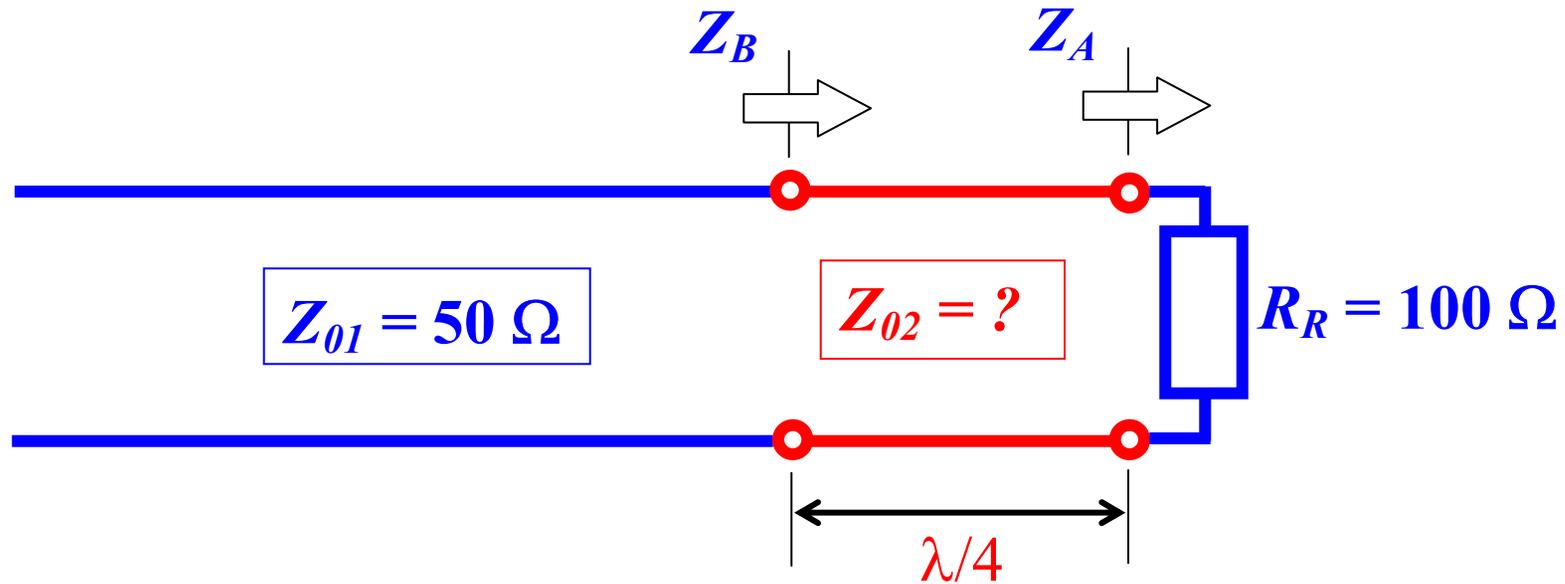
For **impedance matching** we need

$$Z_{01} = \frac{Z_{02}^2}{Z_A} \quad \Rightarrow \quad Z_{02} = \sqrt{Z_{01} Z_A}$$

The characteristic impedance of the transformer is simply the **geometric average** between the characteristic impedance of the original line and the load seen by the transformer.

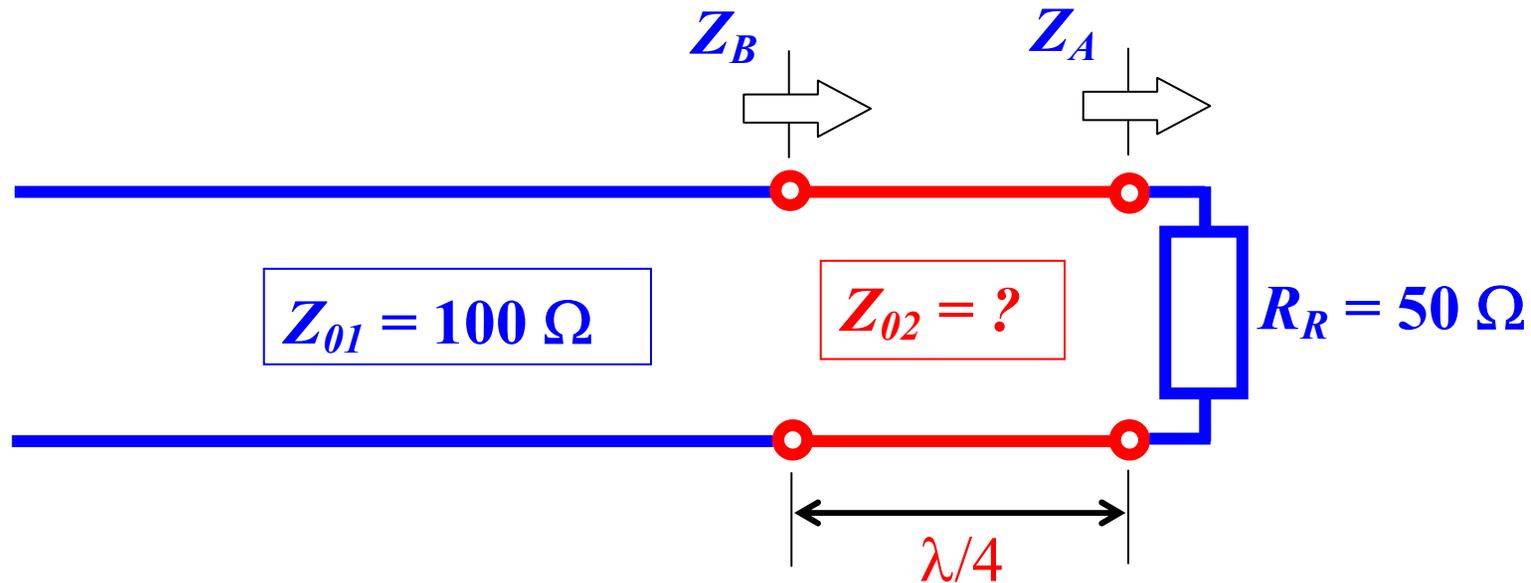
Let's now review some simple examples.

## Real Load Impedance



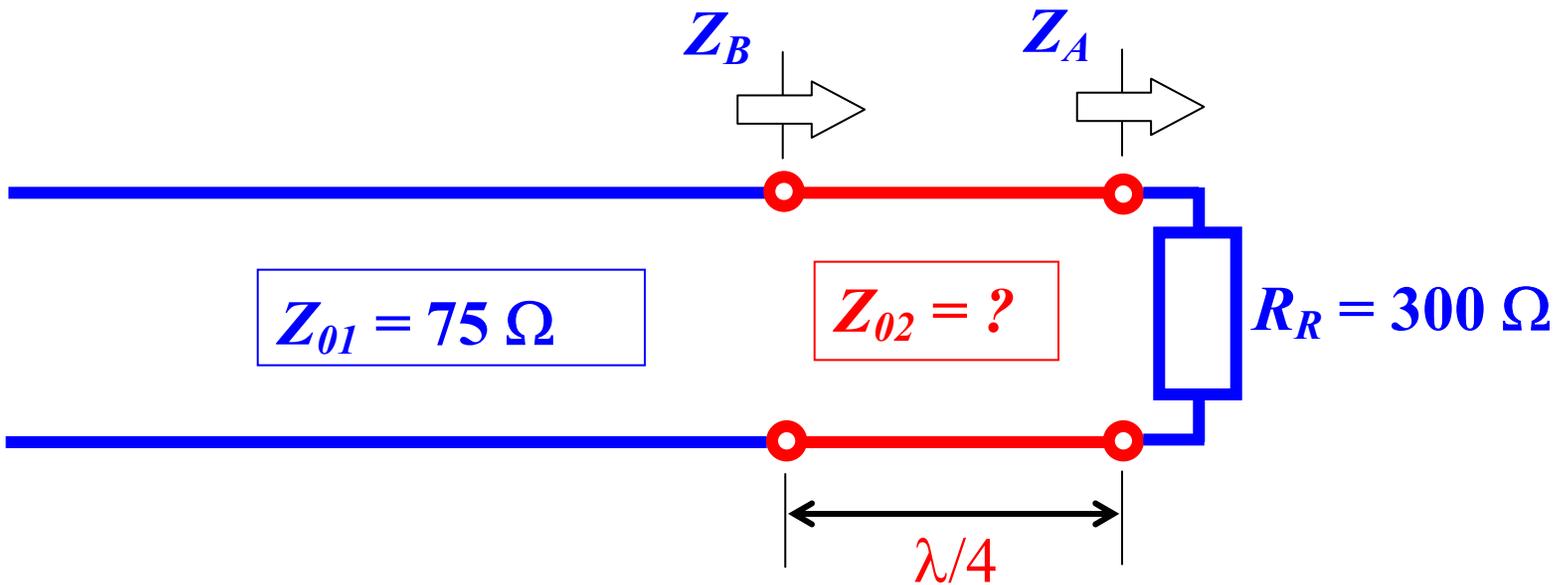
$$Z_B = \frac{Z_{02}^2}{R_R} = Z_{01} \Rightarrow Z_{02} = \sqrt{Z_{01} R_R} = \sqrt{50 \cdot 100} \approx 70.71 \Omega$$

Note that an identical result is obtained by switching  $Z_{01}$  and  $R_R$



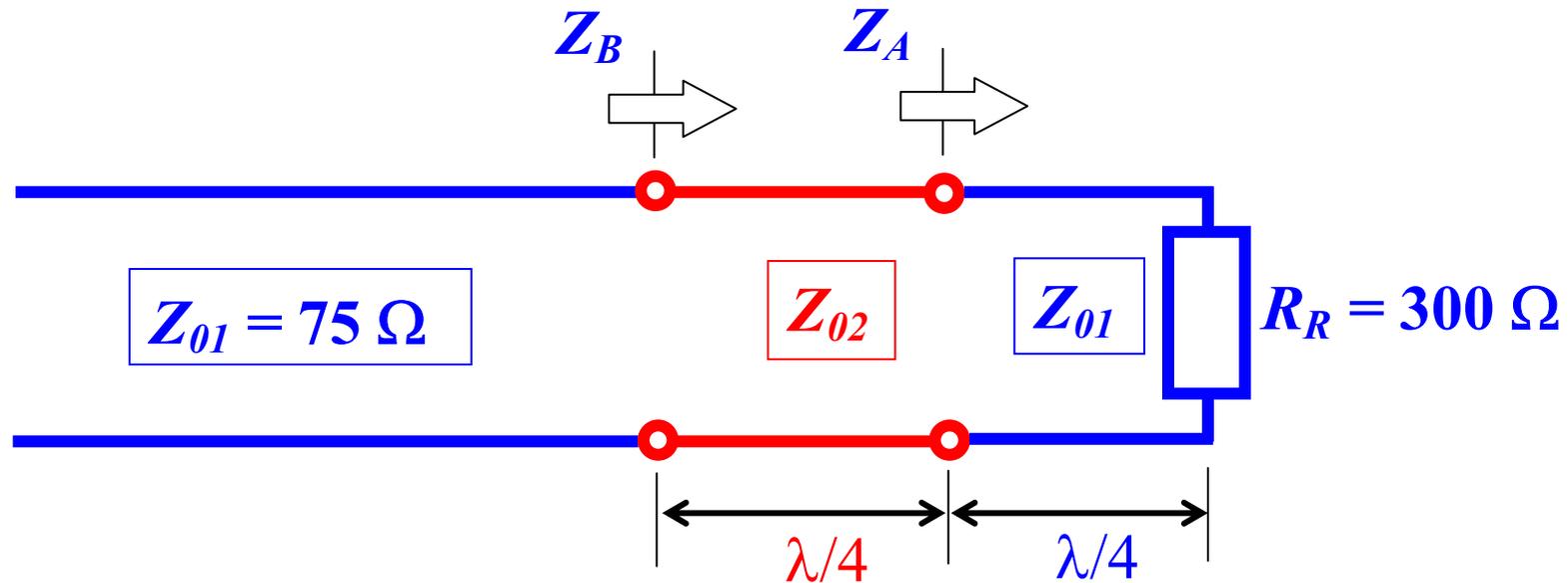
$$Z_B = \frac{Z_{02}^2}{R_R} = Z_{01} \Rightarrow Z_{02} = \sqrt{Z_{01} R_R} = \sqrt{100 \cdot 50} \approx 70.71 \Omega$$

## Another real load case



$$Z_B = \frac{Z_{02}^2}{R_R} = Z_{01} \Rightarrow Z_{02} = \sqrt{Z_{01} R_R} = \sqrt{75 \cdot 300} = 150 \Omega$$

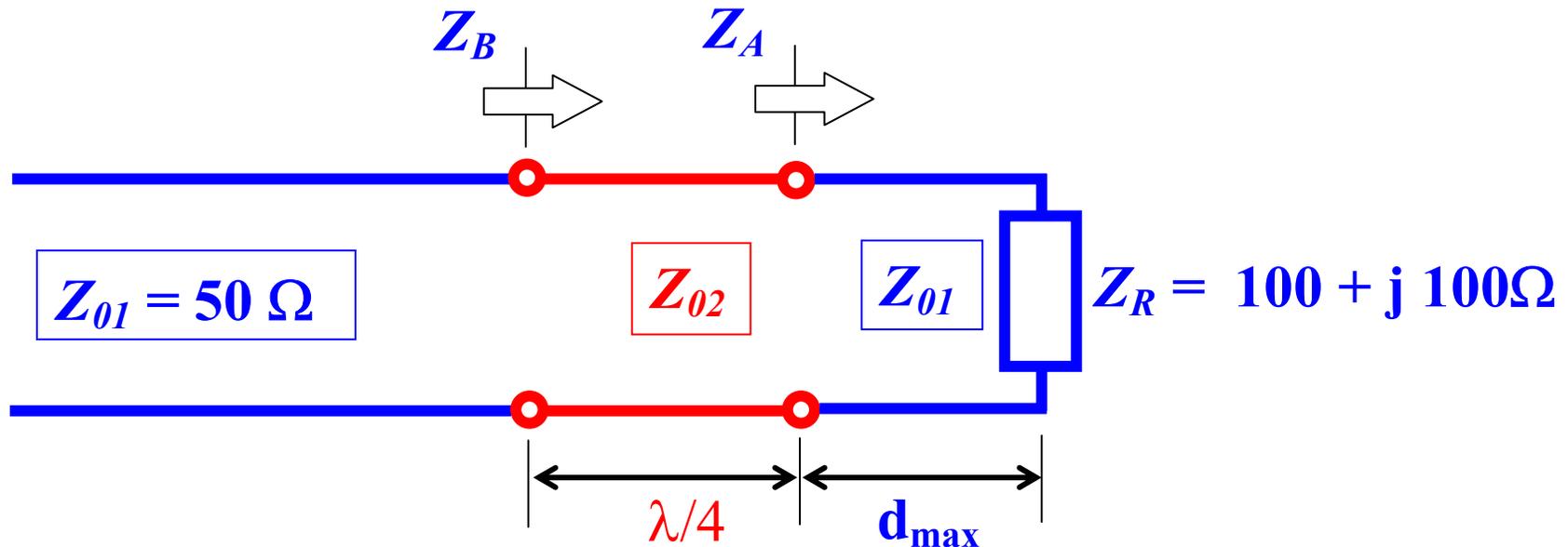
Same impedances as before, but now the transformer is inserted at a distance  $\lambda/4$  from the load (voltage minimum in this case)



$$Z_A = \frac{Z_{01}^2}{R_R} = \frac{75^2}{300} = 18.75 \Omega$$

$$Z_B = \frac{Z_{02}^2}{Z_A} = Z_{01} \Rightarrow Z_{02} = \sqrt{Z_{01} Z_A} = \sqrt{75 \cdot 18.75} = 37.5 \Omega$$

□ **Complex Load Impedance** – Transformer at voltage maximum

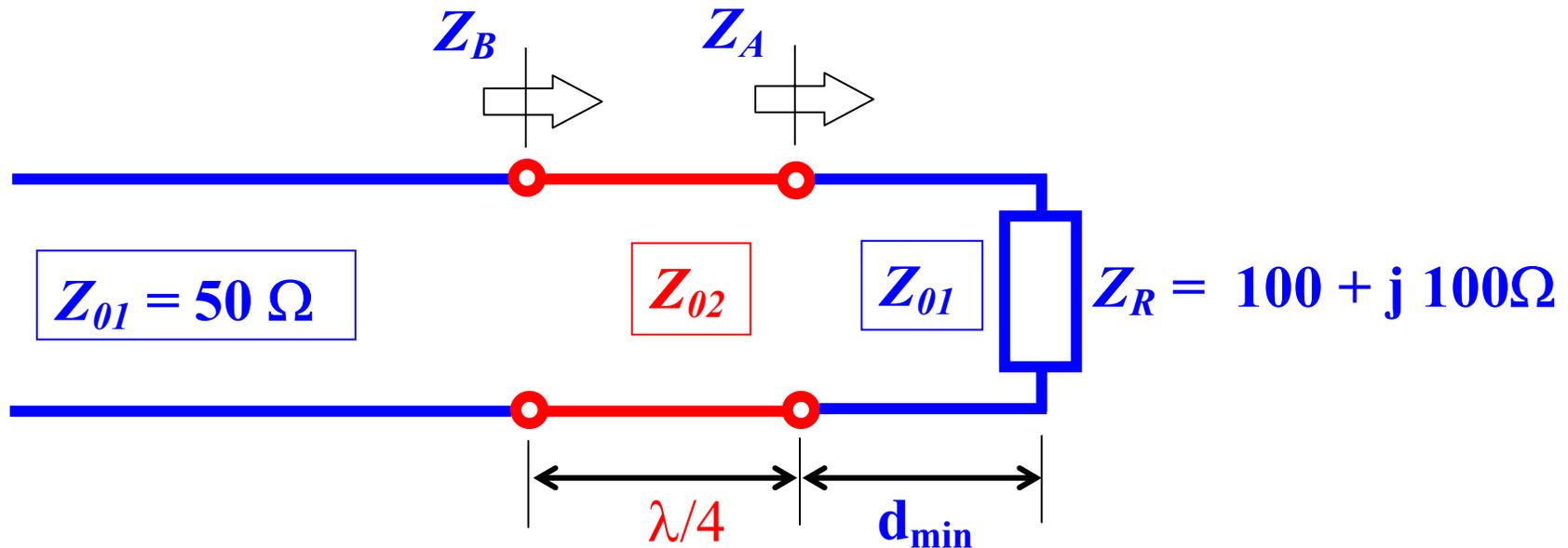


$$|\Gamma_R| = \left| \frac{100 + j100 - 50}{100 + j100 + 50} \right| \approx 0.62$$

$$Z_A = Z_0 \frac{1 + |\Gamma_R|}{1 - |\Gamma_R|} \approx 213.28 \Omega$$

$$Z_{02} = \sqrt{Z_{01} Z_A} = \sqrt{50 \cdot 213.28} = 103.27 \Omega$$

□ **Complex Load Impedance – Transformer at voltage minimum**



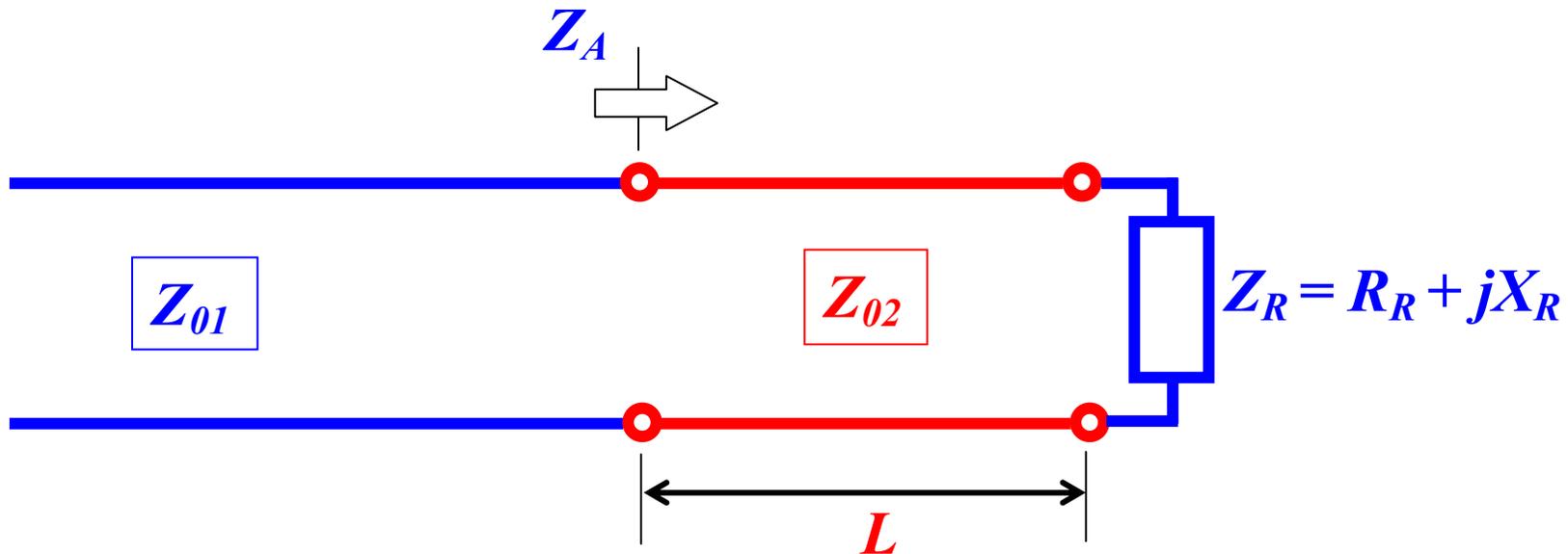
$$|\Gamma_R| = \left| \frac{100 + j100 - 50}{100 + j100 + 50} \right| \approx 0.62$$

$$Z_A = Z_0 \frac{1 - |\Gamma_R|}{1 + |\Gamma_R|} \approx 11.72 \Omega$$

$$Z_{02} = \sqrt{Z_{01} Z_A} = \sqrt{50 \cdot 11.72} = 24.21 \Omega$$

- Generalized Transformer

If it is not important to realize the impedance transformer with a quarter wavelength line, one may try to select a **transmission line** with **appropriate length** and **characteristic impedance**, such that the input impedance is the required real value



$$Z_{01} = Z_A = Z_{02} \frac{R_R + jX_R + jZ_{02} \tan(\beta L)}{Z_{02} + j(R_R + jX_R) \tan(\beta L)}$$

After **separation** of **real** and **imaginary** parts we obtain the equations

$$Z_{02}(Z_{01} - R_R) = Z_{01}X_R \tan(\beta L)$$

$$\tan(\beta L) = \frac{Z_{02}X_R}{Z_{01}R_R - Z_{02}^2}$$

with final **solution**

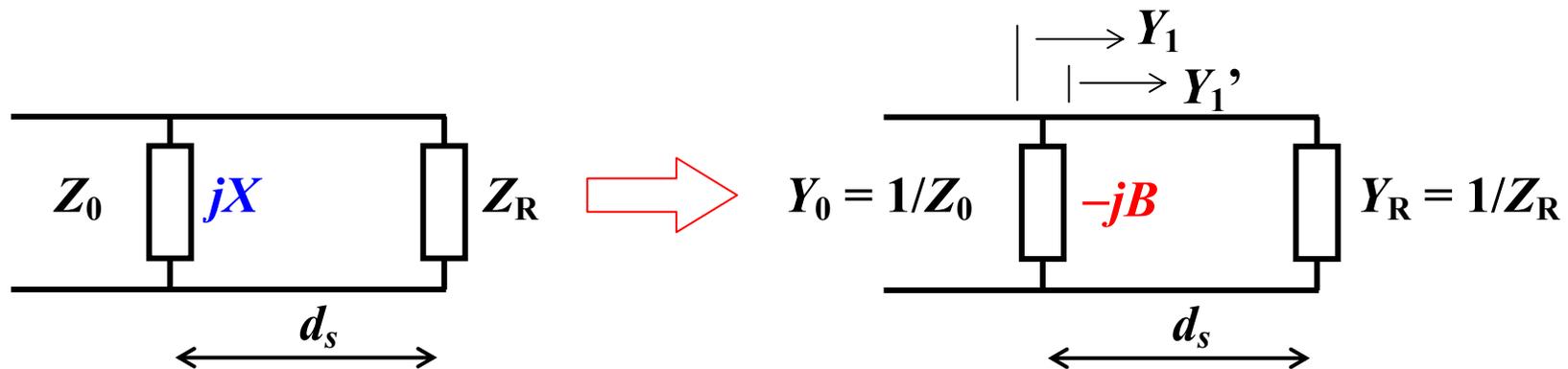
$$Z_{02} = \frac{\sqrt{Z_{01}R_R - R_R^2 - X_R^2}}{\sqrt{1 - R_R / Z_{01}}}$$

$$\tan(\beta L) = \frac{\sqrt{(1 - R_R / Z_{01})(Z_{01}R_R - R_R^2 - X_R^2)}}{X_R}$$

The transformer can be realized as long as the result for  $Z_{02}$  is real. Note that this is also a **narrow band** approach.

## Matching II – Shunt Admittance

We wish to insert a **parallel** (shunt) **reactance** on the transmission line to obtain impedance matching. Since the design involves a parallel circuit, it is more convenient to consider **admittances**:



The shunt may be inserted at locations  $d_s$  where the real part of the line admittance is equal to the characteristic admittance  $Y_0$

$$Y_1' = Y_0 + jB$$

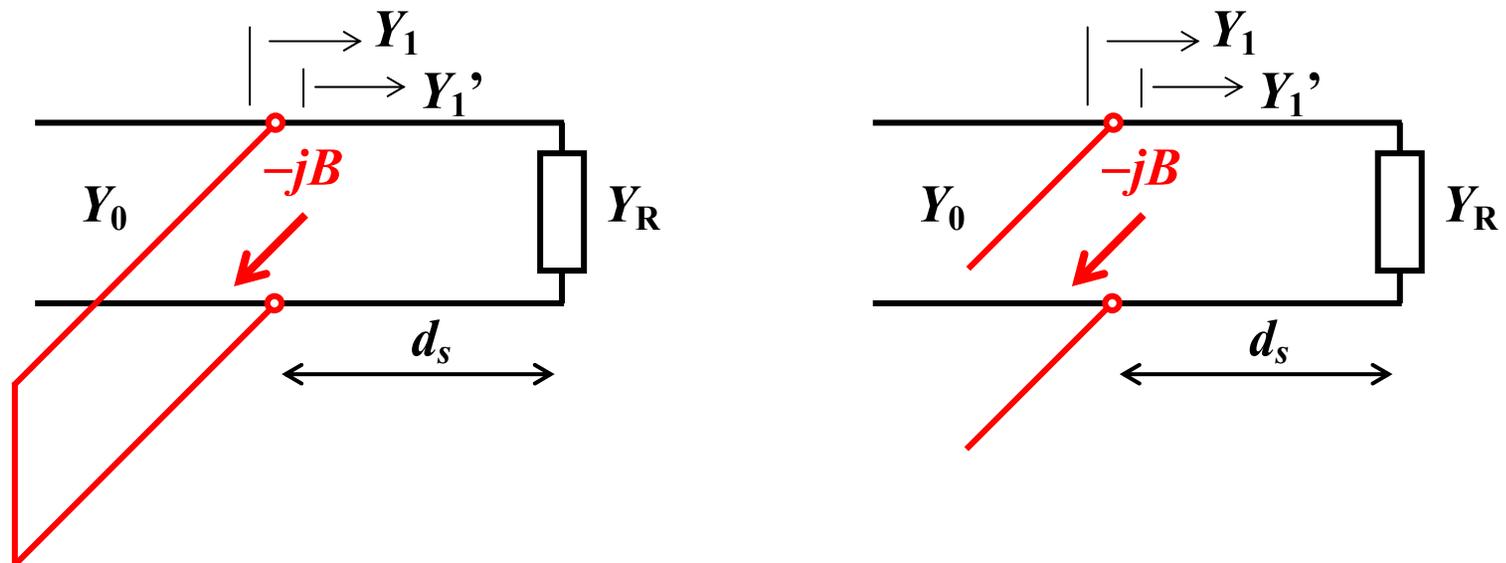
Matching is obtained by using a shunt susceptance  $-jB$  so that

$$Y_1 = [Z(d_s)]^{-1} - jB = Y_1' - jB = Y_0$$

To solve this **design problem**, we need to find the suitable **locations**  $d_s$  (where the real part of the line admittance is equal to  $Y_0$ ) and the corresponding values of the shunt **susceptance**  $-jB$ .

The **shunt element** may be also realized by inserting a **segment** of **transmission line** of appropriate length, called a **stub**.

In order to obtain a pure susceptance, the stub element may consist of a **short-circuited** or an **open-circuited** transmission line with input admittance  $-jB$ .



The **line admittance** at location  $d_s$  can be expressed as a function of **reflection coefficient**

$$Y_1' = Y_0 + jB = \left( Z_0 \frac{1 + \Gamma(d_s)}{1 - \Gamma(d_s)} \right)^{-1} = Y_0 \frac{1 - \Gamma(d_s)}{1 + \Gamma(d_s)}$$

For more general results, we introduce *normalization*:

$$\frac{Y_1'}{Y_0} = y_1' = 1 + jb = \frac{1 - \Gamma(d_s)}{1 + \Gamma(d_s)} = \text{normalized admittance}$$

$$b = \text{normalized susceptance}$$

Then, the line reflection coefficient can be expressed in terms of  $b$

$$y_1' = \frac{1 - \Gamma(d_s)}{1 + \Gamma(d_s)} \Rightarrow \Gamma(d_s) = \frac{1 - y_1'}{1 + y_1'} = \frac{1 - (1 + jb)}{1 + 1 - jb} = \frac{-jb}{2 + jb}$$

Since we know that  $\Gamma(d_s) = \Gamma_R \exp(-j2\beta d_s)$

$$\Gamma_R = |\Gamma_R| \exp(j\theta) = \frac{-jb}{2+jb} \exp(j2\beta d_s)$$

$$= \frac{|b|}{\sqrt{4+b^2}} \exp\left(\mp j\pi/2 - \tan^{-1}(b/2)\right) \exp(j2\beta d_s + j2n\pi)$$

$$\boxed{- \text{ for } b > 0; \quad + \text{ for } b < 0}$$

Added to account for  
periodic behavior

The absolute value of the load reflection coefficient provides  $b$

$$|\Gamma_R| = \frac{|b|}{\sqrt{4+b^2}} \Rightarrow b^2 = \frac{4|\Gamma_R|^2}{1-|\Gamma_R|^2} \Rightarrow b = \pm \frac{2|\Gamma_R|}{\sqrt{1-|\Gamma_R|^2}}$$

$$B = b \cdot Y_0 = b / Z_0$$

Finally, the phase of the load reflection coefficient yields  $d_s$

$$\angle \Gamma_R = \theta = \mp \pi/2 + 2 \beta d_s - \tan^{-1}(b/2) + 2 n \pi$$

$$\Rightarrow 2 \beta d_s = \frac{4\pi}{\lambda} d_s = \theta \mp \pi/2 - \tan^{-1}(b/2) - 2 n \pi$$

$$d_s = \frac{\lambda}{4\pi} (\theta \pm \pi/2 + \tan^{-1}(b/2) - 2 n \pi)$$

$\uparrow$ $+ \text{ for } b > 0; \quad - \text{ for } b < 0$
--

The **last term** accounting for **periodic** behavior of the solution gives

$$\frac{\lambda}{4\pi} 2 n \pi = n \frac{\lambda}{2}$$

indicating that the **solutions repeat** every  $\lambda/2$  along the line.